

RJK4013DPE

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1513-0100 Rev.1.00 Feb 02, 2007

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK(S)-(1)) 1. Gate 2. Drain 3. Source 4. Drain W.DZSC.COM

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	400	V	
Gate to source voltage	V _{GSS}	±30	V	
Drain current	C.G. I _D	17	А	
Drain peak current	I _{D (pulse)} Note1	51	А	
Body-drain diode reverse drain current	I _{DR}	17	А	
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	51	A	
Avalanche current	I _{AP} Note3	6	A	
Avalanche energy	E _{AR} Note3	2	mJ mJ	
Channel dissipation	Pch Note2	100	WWW	
Channel to case thermal impedance	θch-c	1.25	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

WW.DZSC.CO Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C



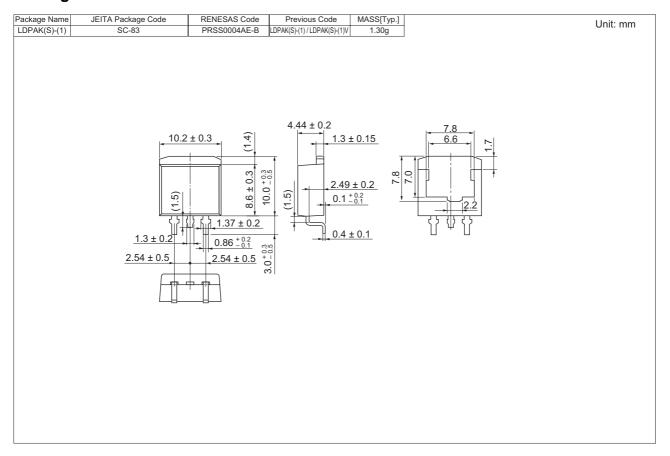
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	400	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	V _{DS} = 400 V, V _{GS} = 0
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R _{DS(on)}	_	0.25	0.30	Ω	$I_D = 8.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	1450	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	175	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	21	_	pF	
Turn-on delay time	t _{d(on)}	_	33	_	ns	I _D = 8.5 A
Rise time	t _r	_	28	_	ns	$V_{GS} = 10 \text{ V}$ $R_L = 23.5 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	84	_	ns	
Fall time	t _f	_	15	_	ns	
Total gate charge	Qg	_	38	_	nC	V _{DD} = 320 V
Gate to source charge	Qgs	_	8	_	nC	V _{GS} = 10 V I _D = 17 A
Gate to drain charge	Qgd	_	17	_	nC	
Body-drain diode forward voltage	V_{DF}	_	0.9	1.5	V	$I_F = 17 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	260	_	ns	$I_F = 17 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A/}\mu\text{s}$

Notes: 4. Pulse test

Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK4013DPE-00-J3	1000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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